

### 20V N-Channel Enhancement Mode MOSFET

Current

### Features

Voltage

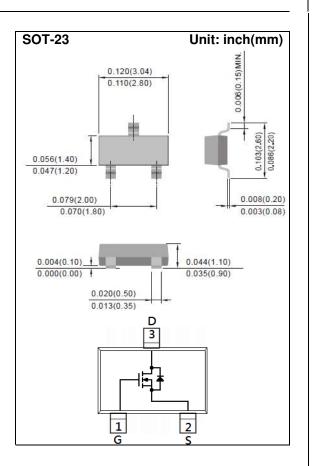
•  $R_{DS(ON)}$ ,  $V_{GS}$ @4.5V,  $I_D$ @4.1A<56m $\Omega$ 

20 V

- $R_{DS(ON)}$ ,  $V_{GS}$ @2.5V,  $I_D$ @2.8A<68m $\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}$ @1.8V,  $I_D$ @1.5A<95m $\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC61249 standard

### **Mechanical Data**

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

4.1A

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	20	N	
Gate-Source Voltage	V <sub>GS</sub>	<u>+</u> 12	V		
Continuous Drain Current		I <sub>D</sub>	4.1	— A	
Pulsed Drain Current		I <sub>DM</sub>	16.4		
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		$T_{J}, T_{STG}$	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup>		R <sub>eja</sub>	100	°C/W	



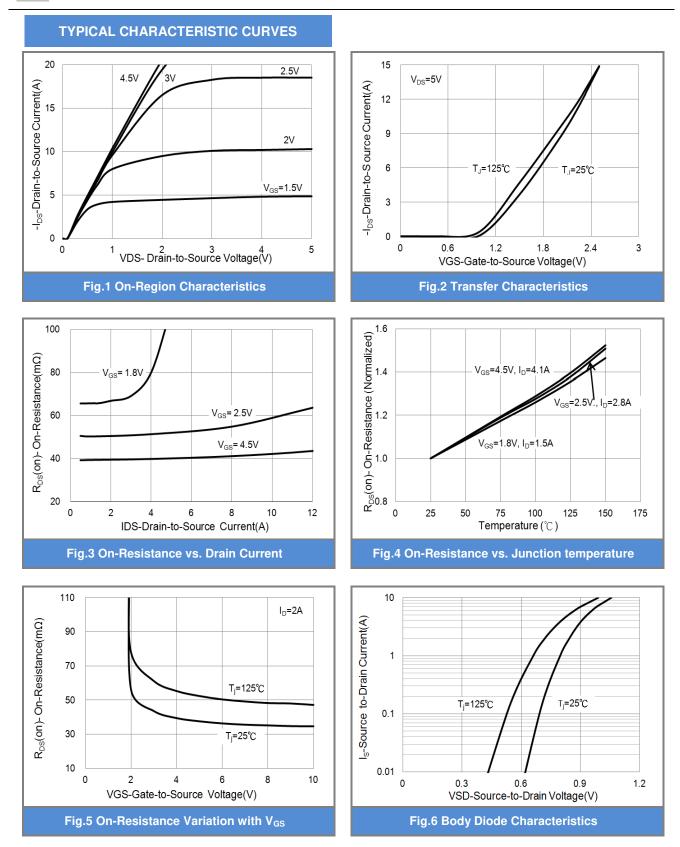
## **Electrical Characteristics** (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}$ =0V, I <sub>D</sub> =250uA	20	-	- v	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}, I_{D}=250uA$	0.4	0.66	1.2	v
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.1A	-	41	56	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =2.8A	-	50	68	
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =1.5A	-	66	95	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =20V, $V_{GS}$ =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 5)						
Total Gate Charge	Qg		-	4.6	-	nC
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ =10V, I <sub>D</sub> =4.1A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	0.8	-	
Gate-Drain Charge	$Q_gd$		-	1	-	
Input Capacitance	Ciss	└ V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, └ f=1MHZ	-	350	-	pF
Output Capacitance	Coss		-	40	-	
Reverse Transfer Capacitance	Crss		-	29	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	4	-	ns
Turn-On Rise Time	tr	$V_{DD}=10V, I_{D}=4.1A,$	-	47	-	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}=4.5V,$ $R_G=6\Omega^{(Note 1,2)}$	-	18	-	
Turn-Off Fall Time	tf	H <sub>G</sub> =0Ω	-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>		-	-	1.5	А
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.75	1.2	V

NOTES :

- 1. Pulse width<u><</u>300us, Duty cycle<u><</u>2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. ReJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.







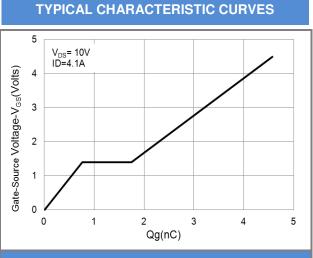


Fig.7 Gate-Charge Characteristics

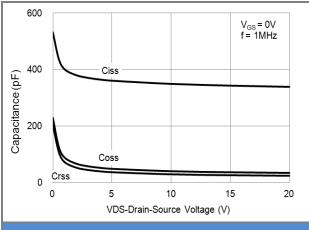
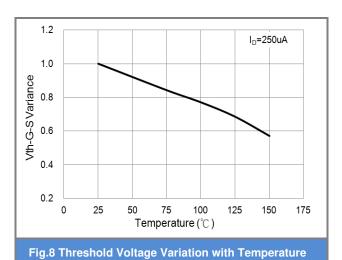


Fig.9 Capacitance vs. Drain-Source Voltage







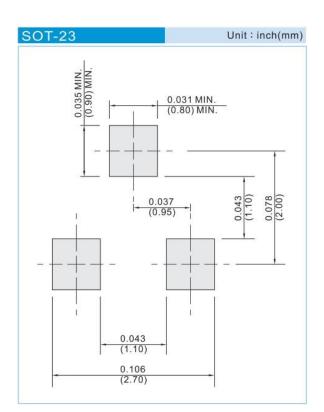




### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3412_R1_00001	SOT-23	3K pcs / 7" reel	A12	Halogen free

### **Mounting Pad Layout**







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